

# Bias Resistor Transistors

## NPN Silicon Surface Mount Transistors With Monolithic Bias Resistor Network

This new series of digital transistors is designed to replace a single device and its external resistor bias network. The BRT (Bias Resistor Transistor) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base-emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space. The device is housed in the SOT-723 package which is designed for low power surface mount applications.

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- The SOT-723 Package can be Soldered using Wave or Reflow.
- Available in 4 mm, 8000 Unit Tape & Reel
- These are Pb-Free Devices.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

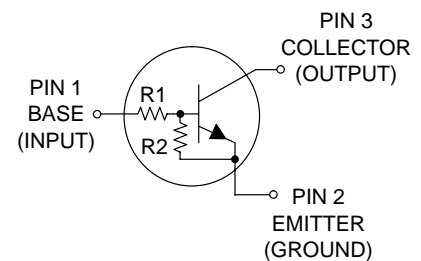
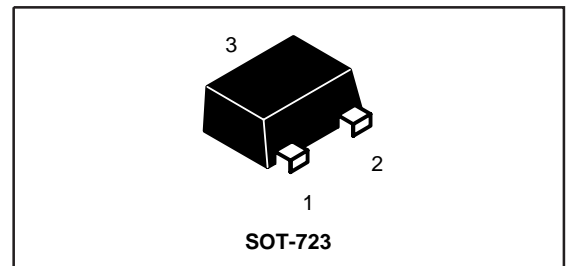
Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CB0}$	50	Vdc
Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current	$I_C$	100	mAdc

### THERMAL CHARACTERISTICS

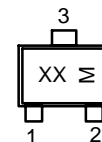
Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	260 (Note 1) 600 (Note 2) 2.0 (Note 1) 4.8 (Note 2)	mW mW/ $^\circ\text{C}$
Thermal Resistance – Junction-to-Ambient	$R_{\theta JA}$	480 (Note 1) 205 (Note 2)	$^\circ\text{C/W}$
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-4 @ Minimum Pad
2. FR-4 @ 1.0 x 1.0 inch Pad

## LDTC114EM3T5G Series S-LDTC114EM3T5G Series



### MARKING DIAGRAM



- xx = Specific Device Code  
M = Date Code

## LDTC114EM3T5G SERIES, S-LDTC114EM3T5G SERIES

### DEVICE MARKING AND RESISTOR VALUES

Device		Marking	R1 (K)	R2 (K)	Package	Shipping
LDTC114EM3T5G	S-LDTC114EM3T5G	8A	10	10	SOT-723	8000/Tape & Reel
LDTC124EM3T5G	S-LDTC124EM3T5G	8B	22	22		
LDTC144EM3T5G	S-LDTC144EM3T5G	8C	47	47		
LDTC114YM3T5G	S-LDTC114YM3T5G	8D	10	47		
LDTC114TM3T5G	S-LDTC114TM3T5G	9A	10	∞		
LDTC143TM3T5G	S-LDTC143TM3T5G	8F	4.7	∞		
LDTC123EM3T5G	S-LDTC123EM3T5G	8H	2.2	2.2		
LDTC143EM3T5G	S-LDTC143EM3T5G	8J	4.7	4.7		
LDTC143ZM3T5G	S-LDTC143ZM3T5G	8K	4.7	47		
LDTC124XM3T5G	S-LDTC124XM3T5G	8L	22	47		
LDTC123JM3T5G	S-LDTC123JM3T5G	8M	2.2	47		
LDTC115EM3T5G	S-LDTC115EM3T5G	8N	100	100		
LDTC144WM3T5G	S-LDTC144WM3T5G	8P	47	22		
LDTC144TM3T5G	S-LDTC144TM3T5G	8T	47	∞		

## LDTCC114EM3T5G SERIES, S-LDTCC114EM3T5G SERIES

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Collector–Base Cutoff Current (V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0)	I <sub>CBO</sub>	–	–	100	nAdc
Collector–Emitter Cutoff Current (V <sub>CE</sub> = 50 V, I <sub>B</sub> = 0)	I <sub>CEO</sub>	–	–	500	nAdc
Emitter–Base Cutoff Current (V <sub>EB</sub> = 6.0 V, I <sub>C</sub> = 0)	I <sub>EBO</sub>	–	–	0.5	mAdc
LDTCC114EM3T5G		–	–	0.2	
LDTCC124EM3T5G		–	–	0.1	
LDTCC144EM3T5G		–	–	0.2	
LDTCC114YM3T5G		–	–	0.9	
LDTCC114TM3T5G		–	–	1.9	
LDTCC143TM3T5G		–	–	2.3	
LDTCC123EM3T5G		–	–	1.5	
LDTCC143EM3T5G		–	–	0.18	
LDTCC143ZM3T5G		–	–	0.13	
LDTCC124XM3T5G		–	–	0.2	
LDTCC123JM3T5G		–	–	0.05	
LDTCC115EM3T5G		–	–	0.13	
LDTCC144WM3T5G		–	–	0.2	
LDTCC144TM3T5G		–	–		
Collector–Base Breakdown Voltage (I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	50	–	–	Vdc
Collector–Emitter Breakdown Voltage (Note 3) (I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	–	–	Vdc

### ON CHARACTERISTICS (Note 3)

DC Current Gain (V <sub>CE</sub> = 10 V, I <sub>C</sub> = 5.0 mA)	LDTCC114EM3T5G LDTCC124EM3T5G LDTCC144EM3T5G LDTCC114YM3T5G LDTCC114TM3T5G LDTCC143TM3T5G LDTCC123EM3T5G LDTCC143EM3T5G LDTCC143ZM3T5G LDTCC124XM3T5G LDTCC123JM3T5G LDTCC115EM3T5G LDTCC144WM3T5G LDTCC144TM3T5G	h <sub>FE</sub>	35 60 80 80 160 160 8.0 15 80 80 80 80 80 80 160	60 100 140 140 350 350 15 30 200 150 140 150 140 350	– – – – – – – – – – – – – – –	
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0.3 mA) (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 5 mA) (I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA)	LDTCC123EM3T5G LDTCC143TM3T5G/LDTCC114TM3T5G/ LDTCC143EM3T5G/LDTCC143ZM3T5G/ LDTCC124XM3T5G/LDTCC144TM3T5G	V <sub>CE(sat)</sub>	–	–	0.25	Vdc
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 kΩ)	LDTCC114EM3T5G LDTCC124EM3T5G LDTCC114YM3T5G LDTCC114TM3T5G LDTCC143TM3T5G LDTCC123EM3T5G LDTCC143EM3T5G LDTCC143ZM3T5G LDTCC124XM3T5G LDTCC123JM3T5G	V <sub>OL</sub>	–	–	0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2 0.2	Vdc
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 3.5 V, R <sub>L</sub> = 1.0 kΩ)	LDTCC144EM3T5G LDTCC144TM3T5G		–	–	0.2 0.2	
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 5.5 V, R <sub>L</sub> = 1.0 kΩ)	LDTCC115EM3T5G		–	–	0.2	
(V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 4.0 V, R <sub>L</sub> = 1.0 kΩ)	LDTCC144WM3T5G		–	–	0.2	

3. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%.

## LDTC114EM3T5G SERIES, S-LDTC114EM3T5G SERIES

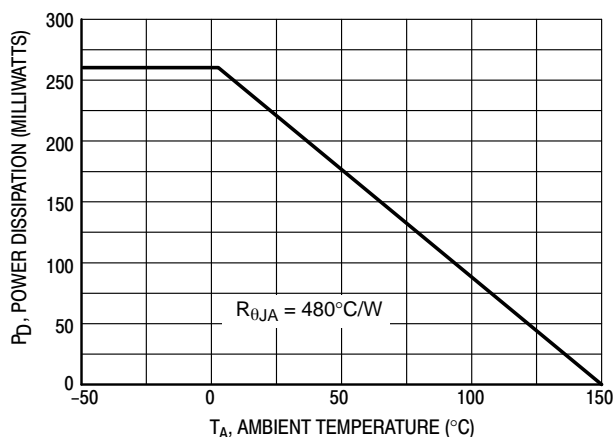
**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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**ON CHARACTERISTICS** (Note 4)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage (off) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.5\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) ( $V_{CC} = 5.0\text{ V}$ , $V_B = 0.25\text{ V}$ , $R_L = 1.0\text{ k}\Omega$ ) LDTC143TM3T5G LDTC143ZM3T5G LDTC114TM3T5G LDTC144TM3T5G	$V_{OH}$	4.9	–	–	Vdc
Input Resistor LDTC114EM3T5G LDTC124EM3T5G LDTC144EM3T5G LDTC114YM3T5G LDTC114TM3T5G LDTC143TM3T5G LDTC123EM3T5G LDTC143EM3T5G LDTC143ZM3T5G LDTC124XM3T5G LDTC123JM3T5G LDTC115EM3T5G LDTC144WM3T5G LDTC144TM3T5G	R1	7.0 15.4 32.9 7.0 7.0 3.3 1.5 3.3 3.3 15.4 1.54 70 32.9 32.9	10 22 47 10 10 4.7 2.2 4.7 4.7 22 2.2 100 47 47	13 28.6 61.1 13 13 6.1 2.9 6.1 6.1 28.6 2.86 130 61.1 61.1	k $\Omega$
Resistor Ratio LDTC114EM3T5G/LDTC124EM3T5G/ LDTC144EM3T5G/LDTC115EM3T5G LDTC114YM3T5G LDTC143TM3T5G/LDTC114TM3T5G/LDTC144TM3T5G LDTC123EM3T5G/LDTC143EM3T5G LDTC143ZM3T5G LDTC124XM3T5G LDTC123JM3T5G LDTC144WM3T5G	$R_1/R_2$	0.8  0.17 – 0.8 0.055 0.38 0.038 1.7	1.0  0.21 – 1.0 0.1 0.47 0.047 2.1	1.2  0.25 – 1.2 0.185 0.56 0.056 2.6	
Input voltage ( $V_{CC} = 5.0\text{ V}$ , $I_O = 100\mu\text{A}$ ) LDTC123JM3T5G	$V_{I(off)}$	–	–	0.5	V
Input voltage ( $V_O = 0.3\text{ V}$ , $I_O = 5\text{ mA}$ ) LDTC123JM3T5G	$V_{I(on)}$	1.1	–	–	V

4. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty Cycle < 2.0%.



**Figure 1. Derating Curve**

# LDT C114EM3T5G SERIES, S-LDT C114EM3T5G SERIES

## TYPICAL ELECTRICAL CHARACTERISTICS – LDT C114EM3T5G

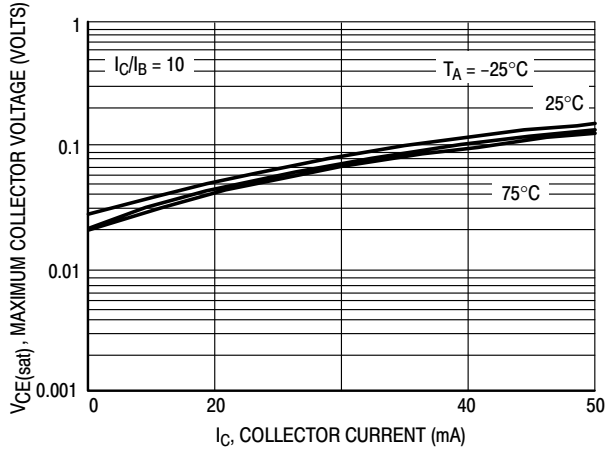


Figure 2.  $V_{CE(sat)}$  versus  $I_C$

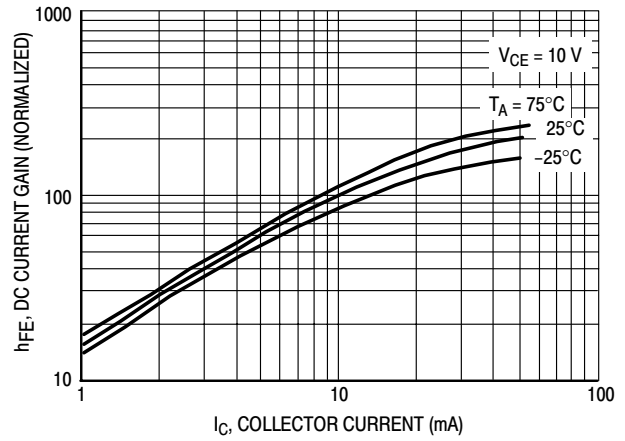


Figure 3. DC Current Gain

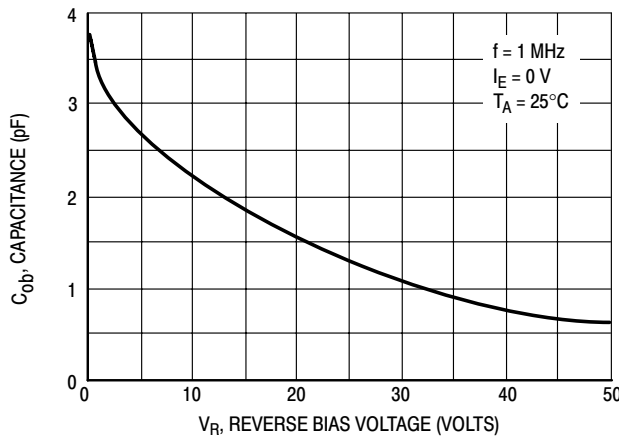


Figure 4. Output Capacitance

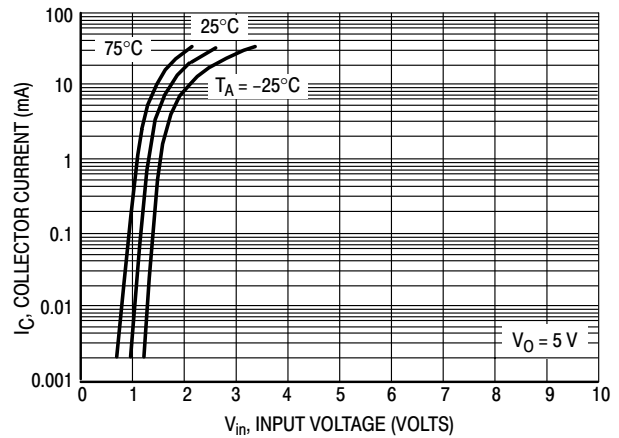


Figure 5. Output Current versus Input Voltage

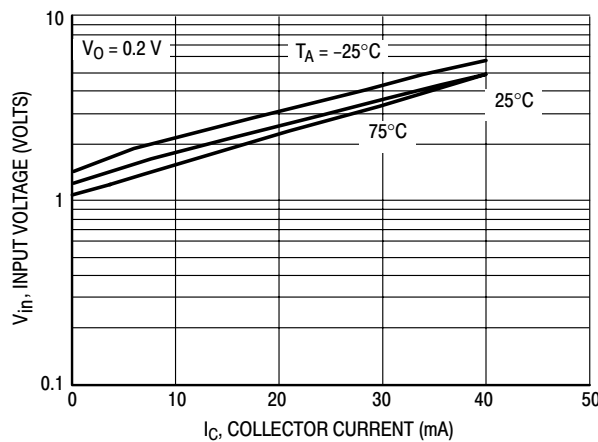


Figure 6. Input Voltage versus Output Current

# LDTC114EM3T5G SERIES, S-LDTC114EM3T5G SERIES

## TYPICAL ELECTRICAL CHARACTERISTICS – LDTC124EM3T5G

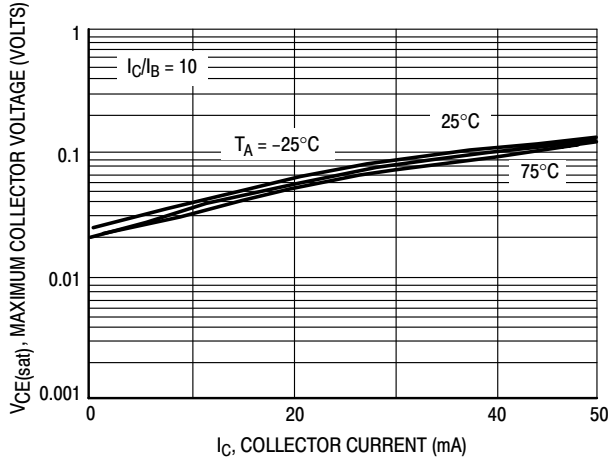


Figure 7.  $V_{CE(sat)}$  versus  $I_C$

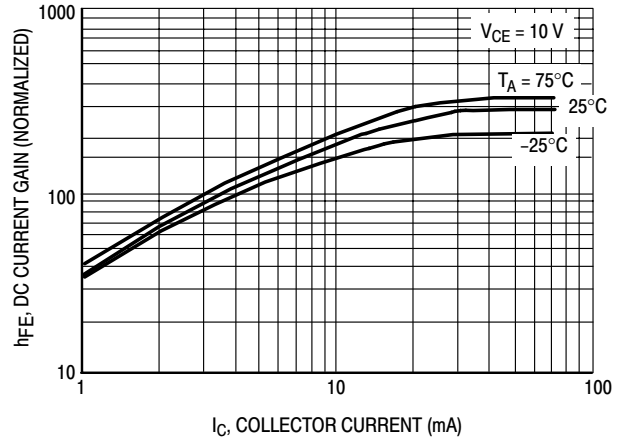


Figure 8. DC Current Gain

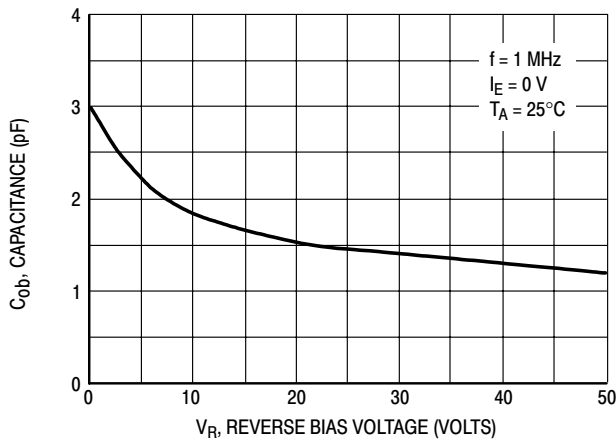


Figure 9. Output Capacitance

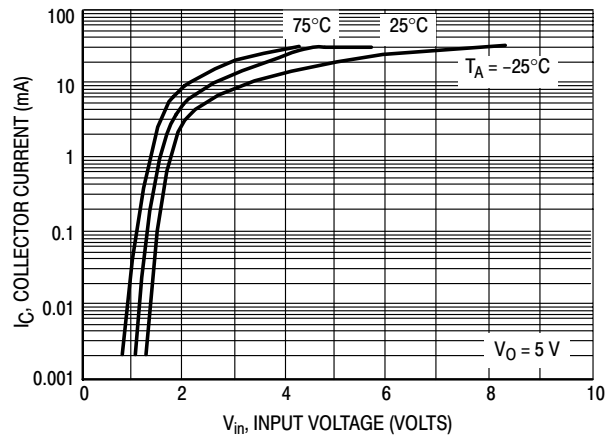


Figure 10. Output Current versus Input Voltage

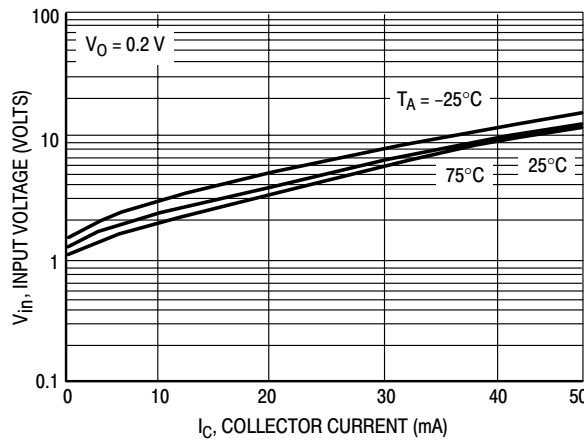


Figure 11. Input Voltage versus Output Current

# LDTTC114EM3T5G SERIES, S-LDTTC114EM3T5G SERIES

## TYPICAL ELECTRICAL CHARACTERISTICS – LDTTC144EM3T5G

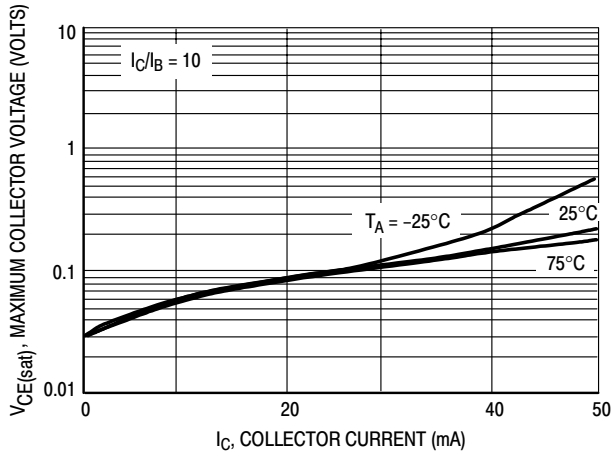


Figure 12.  $V_{CE(sat)}$  versus  $I_C$

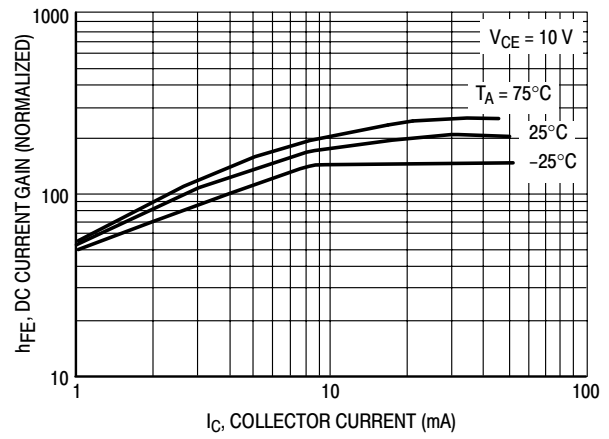


Figure 13. DC Current Gain

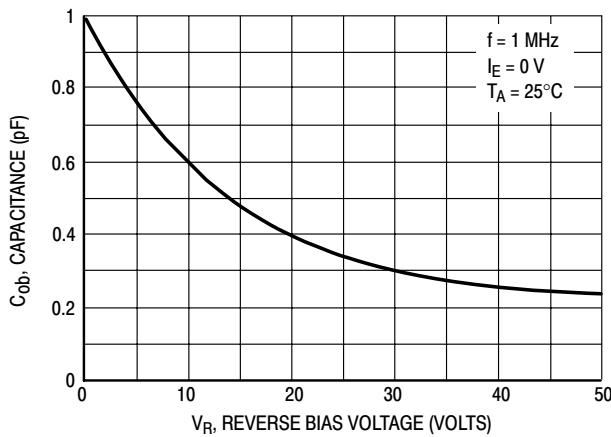


Figure 14. Output Capacitance

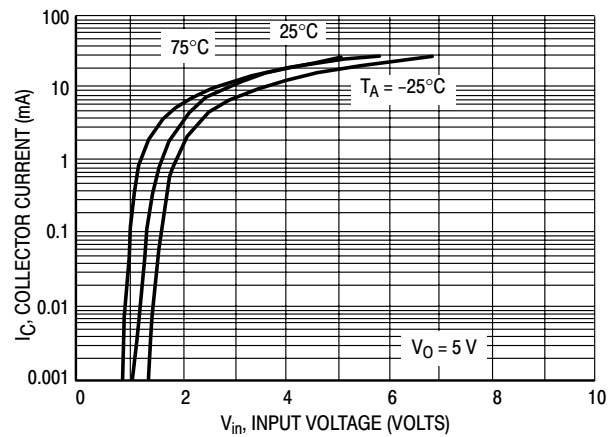


Figure 15. Output Current versus Input Voltage

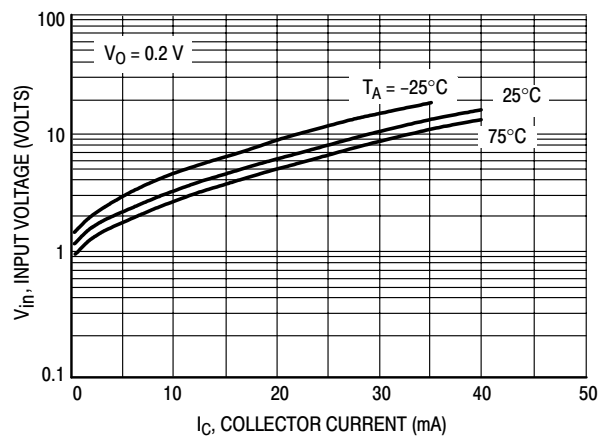


Figure 16. Input Voltage versus Output Current

# LDTC114EM3T5G SERIES, S-LDTC114EM3T5G SERIES

## TYPICAL ELECTRICAL CHARACTERISTICS – LDTC114YM3T5G

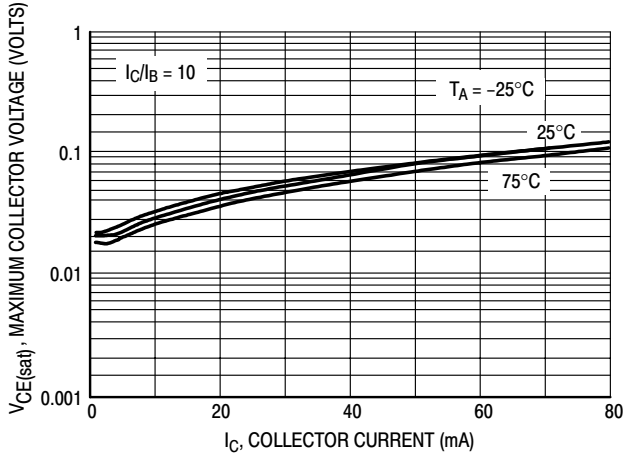


Figure 17.  $V_{CE(sat)}$  versus  $I_C$

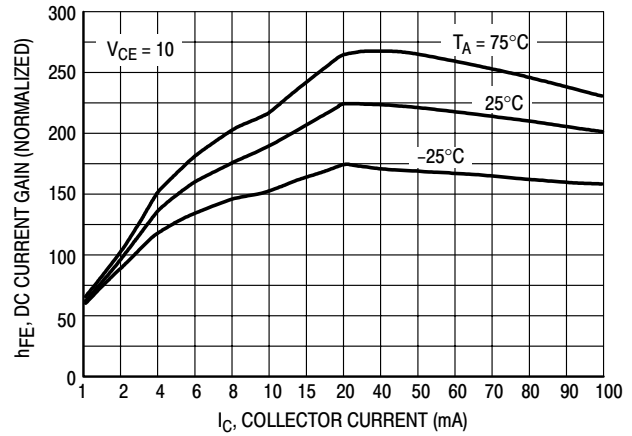


Figure 18. DC Current Gain

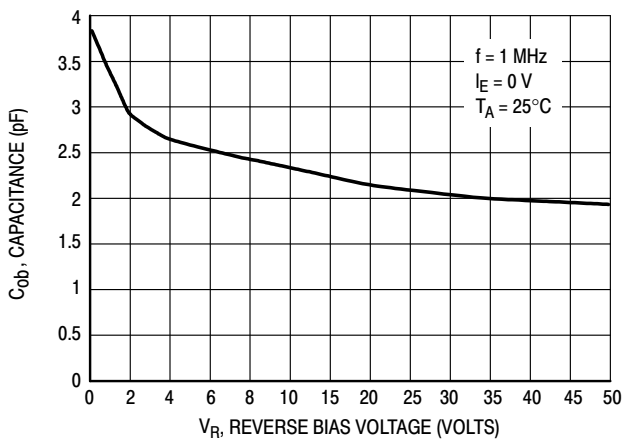


Figure 19. Output Capacitance

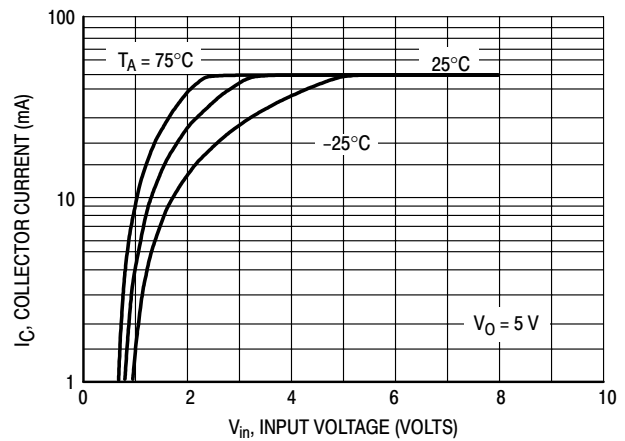


Figure 20. Output Current versus Input Voltage

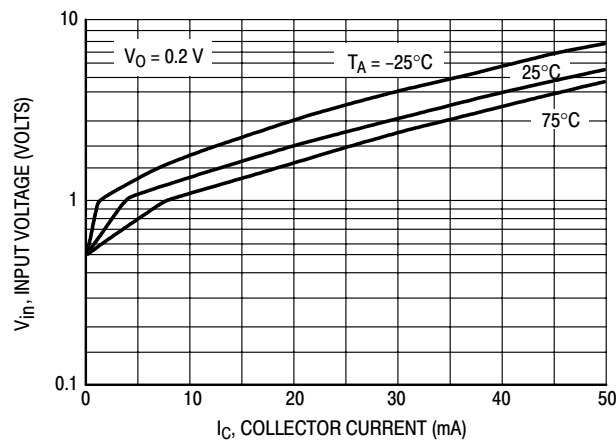


Figure 21. Input Voltage versus Output Current



# LDTTC114EM3T5G SERIES, S-LDTTC114EM3T5G SERIES

## TYPICAL ELECTRICAL CHARACTERISTICS – LDTTC143ZM3T5G

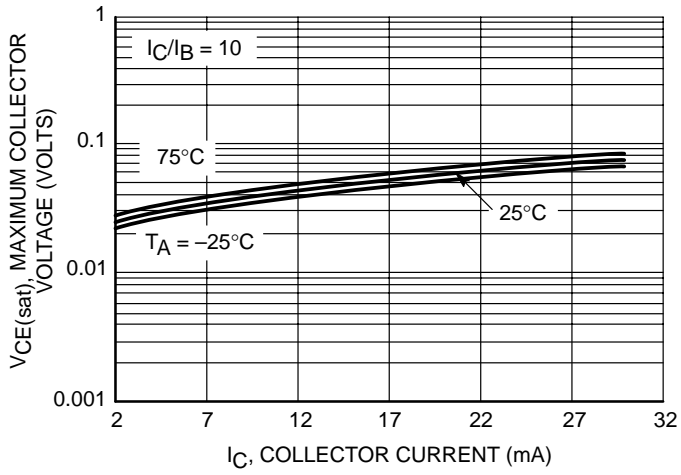


Figure 27.  $V_{CE(sat)}$  vs.  $I_C$

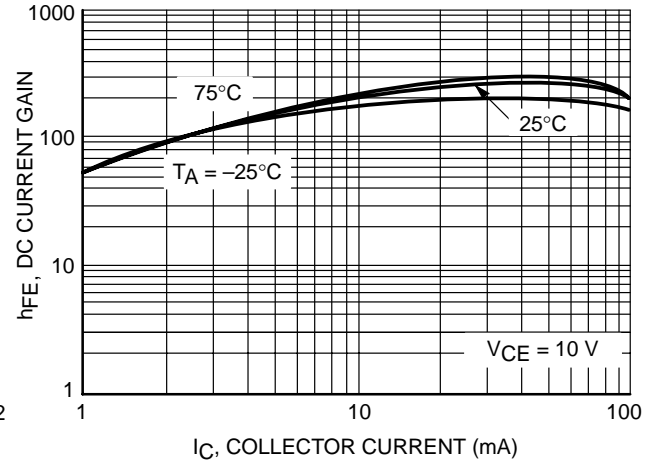


Figure 28. DC Current Gain

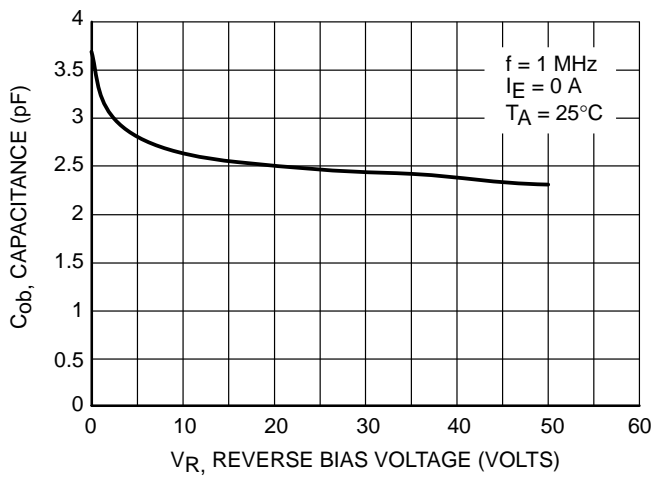


Figure 29. Output Capacitance

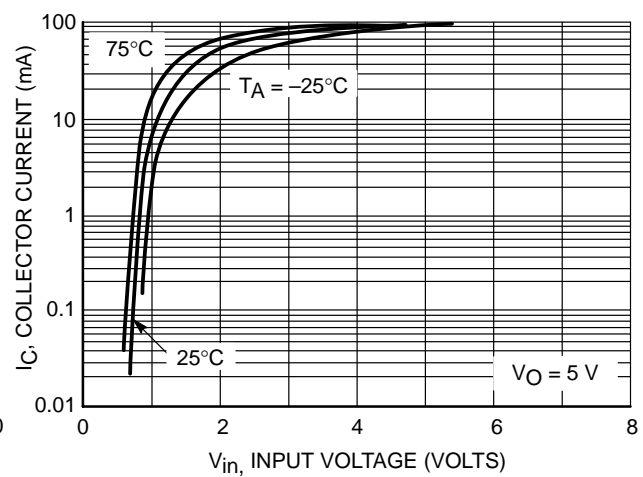


Figure 30. Output Current vs. Input Voltage

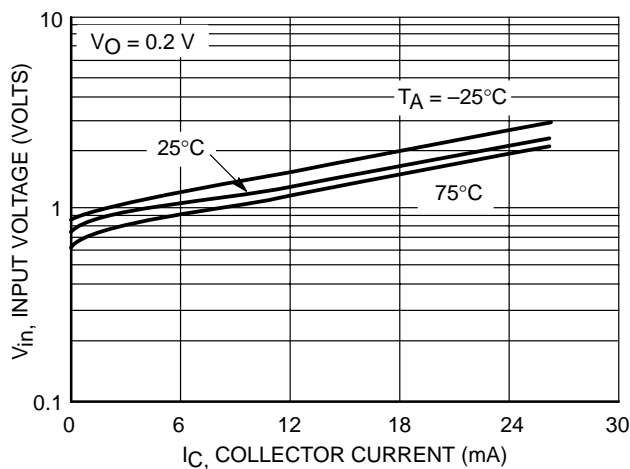


Figure 31. Input Voltage vs. Output Current

# LDTTC114EM3T5G SERIES, S-LDTTC114EM3T5G SERIES

## TYPICAL APPLICATIONS FOR NPN BRTs

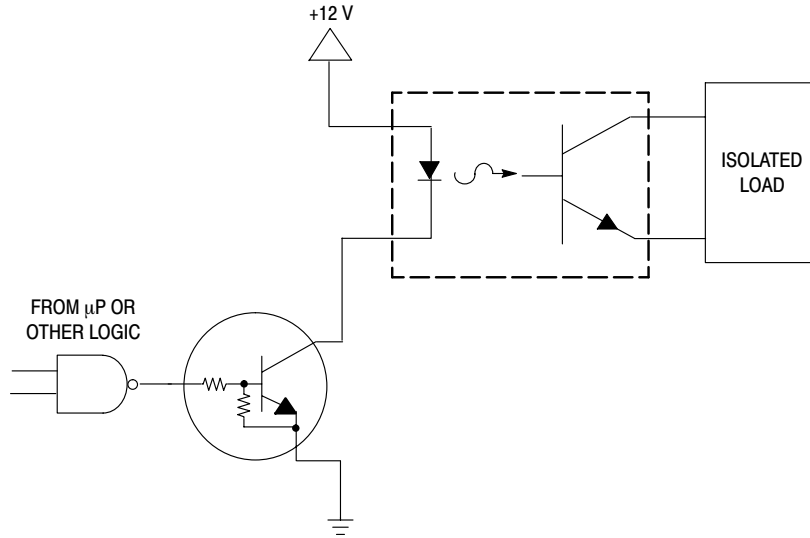


Figure 22. Level Shifter: Connects 12 or 24 Volt Circuits to Logic

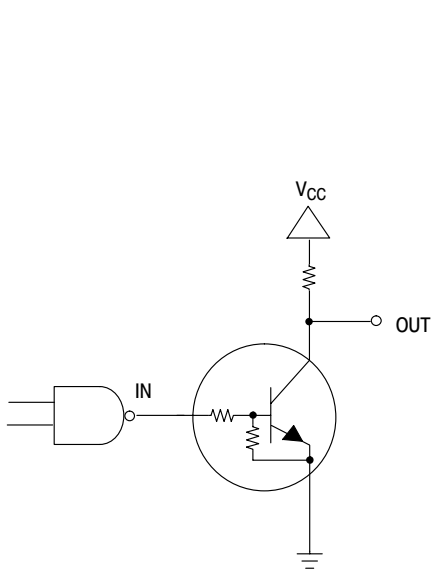


Figure 23. Open Collector Inverter: Inverts the Input Signal

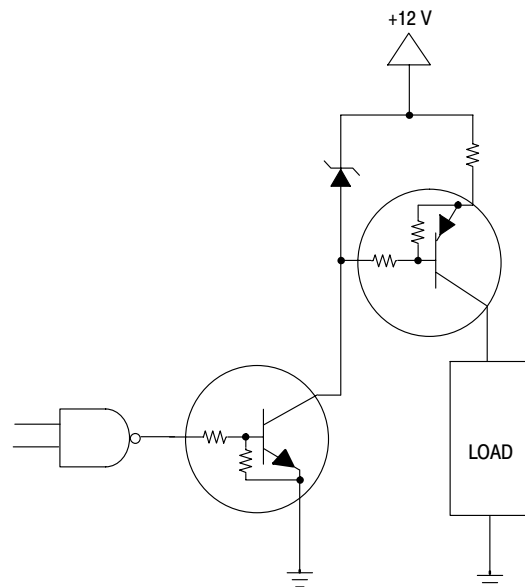
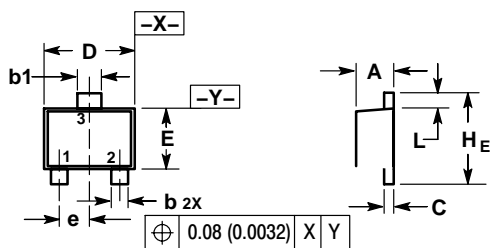


Figure 24. Inexpensive, Unregulated Current Source

# LDT C114EM3T5G SERIES, S-LDT C114EM3T5G SERIES

## PACKAGE DIMENSIONS

### SOT-723



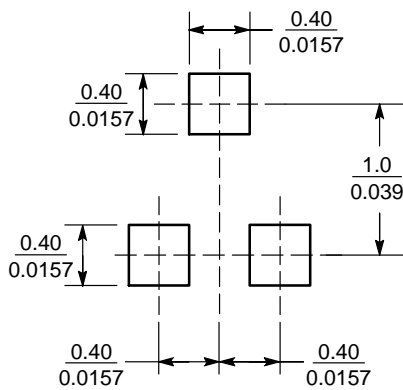
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
b	0.15	0.20	0.27	0.0059	0.0079	0.0106
b1	0.25	0.3	0.35	0.010	0.012	0.014
C	0.07	0.12	0.17	0.0028	0.0047	0.0067
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.75	0.80	0.85	0.03	0.032	0.034
e	0.40 BSC			0.016 BSC		
H E	1.15	1.20	1.25	0.045	0.047	0.049
L	0.15	0.20	0.25	0.0059	0.0079	0.0098

- PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

## SOLDERING FOOTPRINT



( mm / inches )

**DISCLAIMER**

- Before you use our Products, you are requested to carefully read this document and fully understand its contents. LRC shall not be in any way responsible or liable for failure, malfunction or accident arising from the use of any LRC's Products against warning, caution or note contained in this document.
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